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TAIWAN SEMICONDUCTOR

RoHS COMPLIANCE

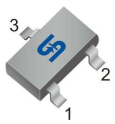
TSH253

High Sensitivity Omni-Polar Hall Effect Switch

TO-92S

Pin Definition:
1. V_{CC}
2. GND
3. Output

SOT-23



Pin Definition:
1. V_{CC}
2. Output
3. GND

Description

TSH253 Hall-effect sensor is a temperature stable, stress-resistant switch. Superior high-temperature performance is made possible through a dynamic offset cancellation that utilizes chopper-stabilization. This method reduces the offset voltage normally caused by device over molding, temperature dependencies, and thermal stress. TSH253 includes the following on a single silicon chip: voltage regulator, Hall voltage generator, small-signal amplifier, chopper stabilization, Schmitt trigger, open-drain output. Advanced CMOS wafer fabrication processing is used to take advantage of low-voltage requirements, component matching, very low input-offset errors, and small component geometries.

Features

- CMOS Hall IC Technology
- Solid-State Reliability much better than reed switch
- Omni polar output switches with absolute value of North or South pole from magnet
- Operation down to 1.8 V and Max at 6V.
- High Sensitivity for reed switch replacement
- ESD HBM ±4KV Min

Ordering Information

Part No.	Package	Packing
TSH253CT B0G	TO-92S	1Kpcs / Bulk Bag
TSH253CX RFG	SOT-23	3Kpcs / 7" Reel

Note: "G" denote for Halogen Free Product

Application

- Solid state switch, Revolution counter
- Lid close sensor for power supply devices
- Magnet proximity sensor for reed switch replacement in high duty cycle applications.
- Safety Key on sporting equipment
- Speed sensor, Position Sensor, Rotation Sensor

Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

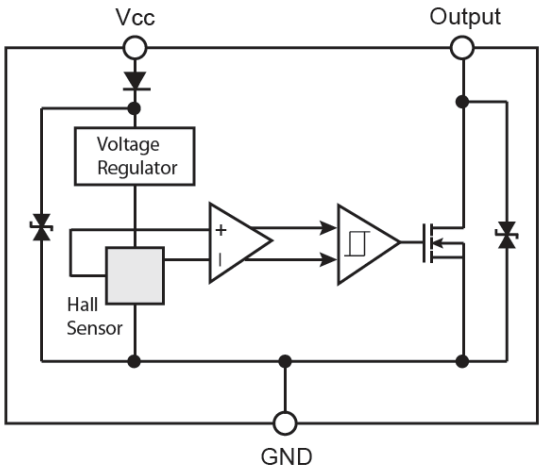
Characteristics		Limit	Value	Unit
Supply voltage		V_{CC}	6	V
Output Voltage		V_{OUT}	6	V
Reverse voltage		$V_{CC/OUT}$	-0.3	V
Magnetic flux density			Unlimited	Gauss
Output current		I_{OUT}	1	mA
Operating Temperature Range		T_{OPR}	-40 to +85	°C
Storage temperature range		T_{STG}	-55 to +150	°C
Maximum Junction Temp		T_J	150	°C
Thermal Resistance - Junction to Ambient	TO-92S	θ_{JA}	206	°C/W
	SOT-23		543	
Thermal Resistance - Junction to Case	TO-92S	θ_{JC}	148	°C/W
	SOT-23		410	
Package Power Dissipation	TO-92S	P_D	606	mW
	SOT-23		230	

Note: Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.

TSH253

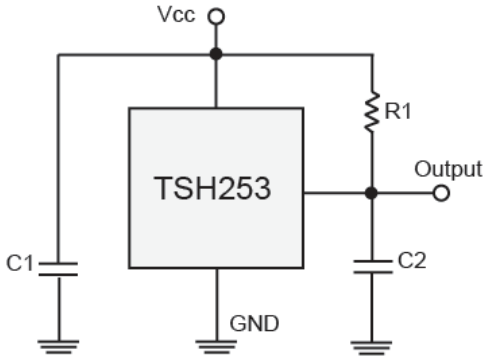
High Sensitivity Omni-Polar Hall Effect Switch

Block Diagram



Note: Static sensitive device; please observe ESD precautions. Reverse VDD protection is not included. For reverse voltage protection, a 100Ω resistor in series with VDD is recommended.

Typical Application Circuit



C1 : 10nF
C2 : 100pF
R1 : 10KΩ

Electrical Specifications (DC Operating Parameters : T_A=+25°C,V_{CC}=5V)

Parameters	Test Conditions	Min	Typ	Max	Units
Supply Voltage	Operating	1.8	--	6	V
Supply Current	Average	--	2.6	6.0	mA
Output Low Voltage	I_{OUT}=0.5mA	--	--	200	mV
Output Leakage Current	I_{OFF} B<B_{RP}, V_{OUT} = 3V	--	--	10	uA
Output Rise Time	R_L=10kΩ, C_L =20pF	--	--	0.45	uS
Output Fall Time	R_L=10kΩ; C_L =20pF	--	--	0.45	uS
Electro-Static Discharge	HBM	4	--	--	KV

TSH253

High Sensitivity Omni-Polar Hall Effect Switch

Magnetic Specifications (TSH253CT)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Operating Point	B_{OPS}	S pole to branded side, B > B_{OP}, Vout On		30	60	Gauss
	B_{OPN}	N pole to branded side, B > B_{OP}, Vout On	-60	-30		Gauss
Release Point	B_{RPS}	S pole to branded side, B < B_{RP}, Vout Off	5	25		Gauss
	B_{RPN}	N pole to branded side, B < B_{RP}, Vout Off		-25	-5	Gauss
Hysteresis	B_{HYS}	|BOPx - BRPx|		5		Gauss

Note: 1G (Gauss) = 0.1mT (millitesta)

Magnetic Specifications (TSH253CX)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Operating Point	B_{OPS}	N pole to branded side, B > B_{OP}, Vout On	--	30	60	Gauss
	B_{OPN}	S pole to branded side, B > B_{OP}, Vout On	-60	-30	--	Gauss
Release Point	B_{RPS}	N pole to branded side, B < B_{RP}, Vout Off	5	25	--	Gauss
	B_{RPN}	S pole to branded side, B < B_{RP}, Vout Off	--	-25	-5	Gauss
Hysteresis	B_{HYS}	|BOPx - BRPx|	--	5	--	Gauss

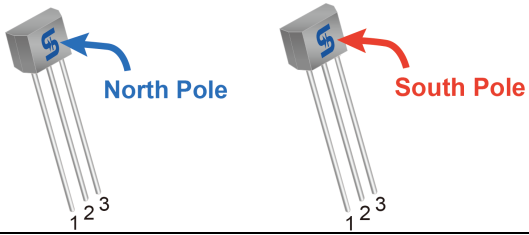
Note: 1G (Gauss) = 0.1mT (millitesta)

Output Behavior versus Magnetic Pole

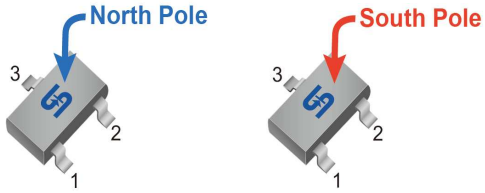
DC Operating Parameters: T_A = -40 to 125°C, V_{CC} = 1.8V ~ 6V

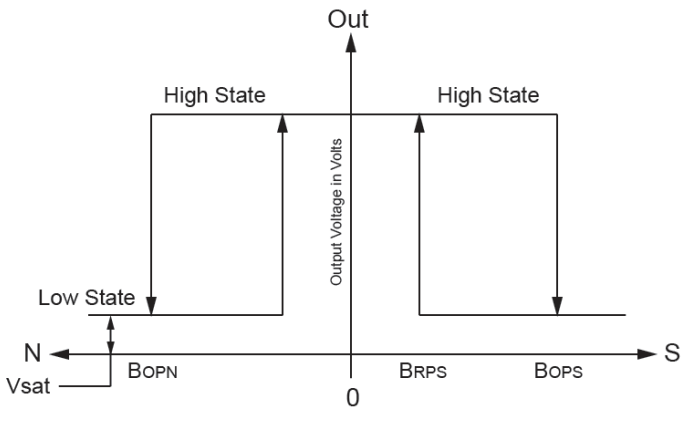
Parameter	Test condition	OUT
South pole	B<Bop[(-60)~(-5)]	Low
Null or weak magnetic field	B=0 or B < BRP	Open(Pull-up Voltage)
North pole	B>Bop(60~5)	Low

TO-92S



SOT-23





Characteristic Performance

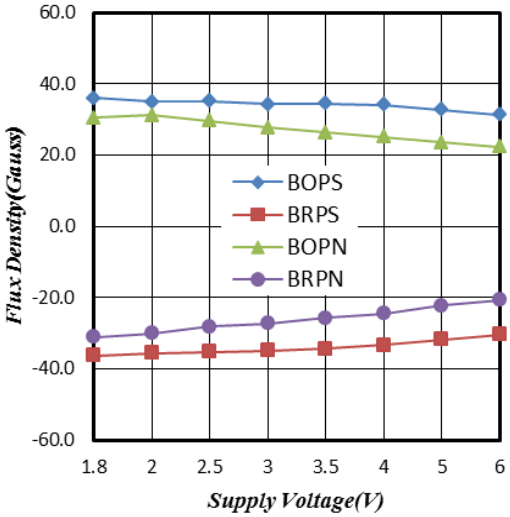


Figure 1. Supply Voltage vs. Flux Density

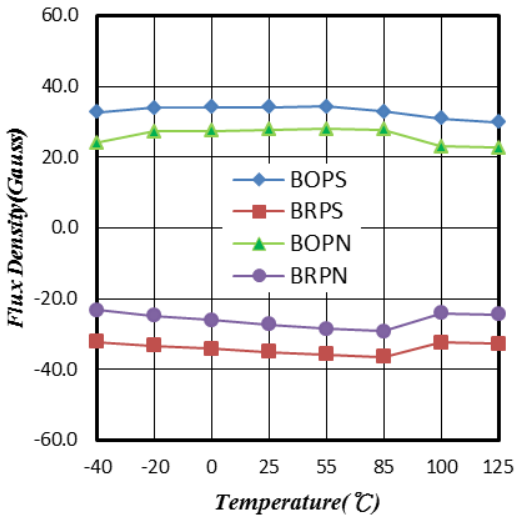


Figure 2. Temperature vs. Flux Density

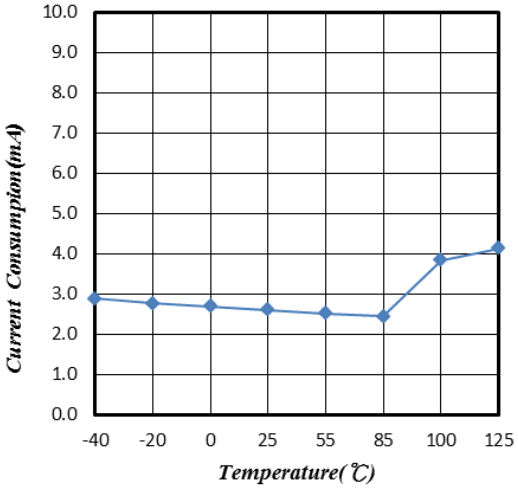


Figure 3. Supply Current vs. Temperature

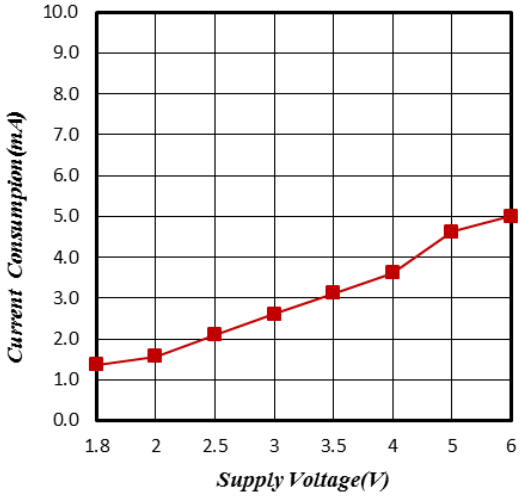


Figure 4. Supply Current vs. Supply Voltage

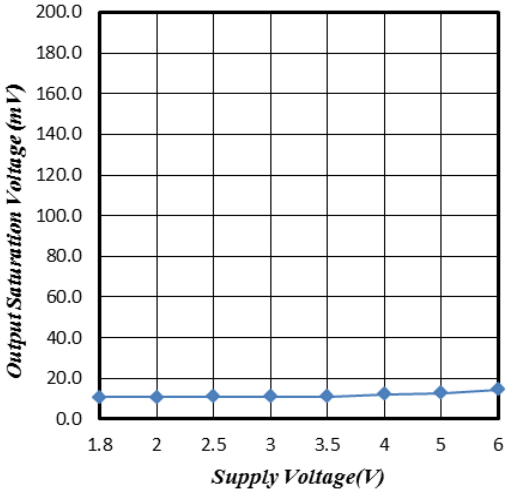


Figure 5. Output Saturation Voltage vs. Supply Voltage

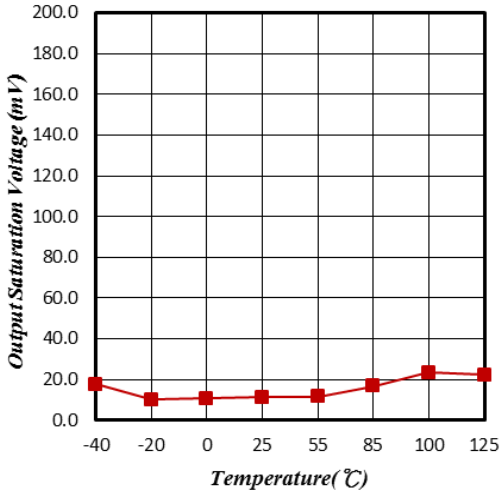


Figure 6. Output Saturation Voltage vs. Temperature

Characteristic Performance

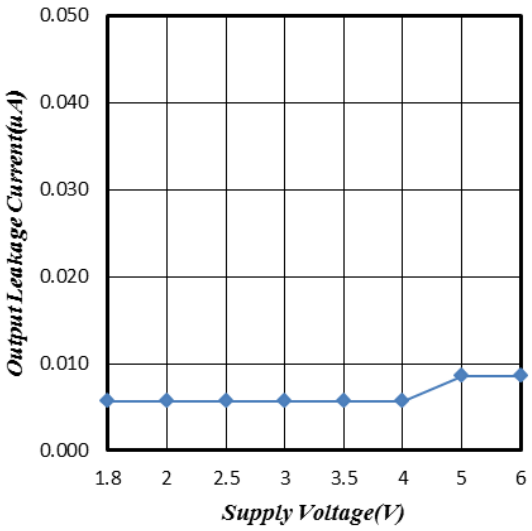


Figure 7. Output Leakage Current vs. Supply Voltage

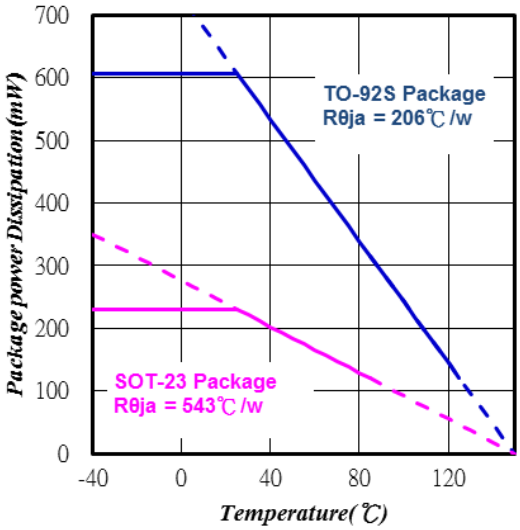
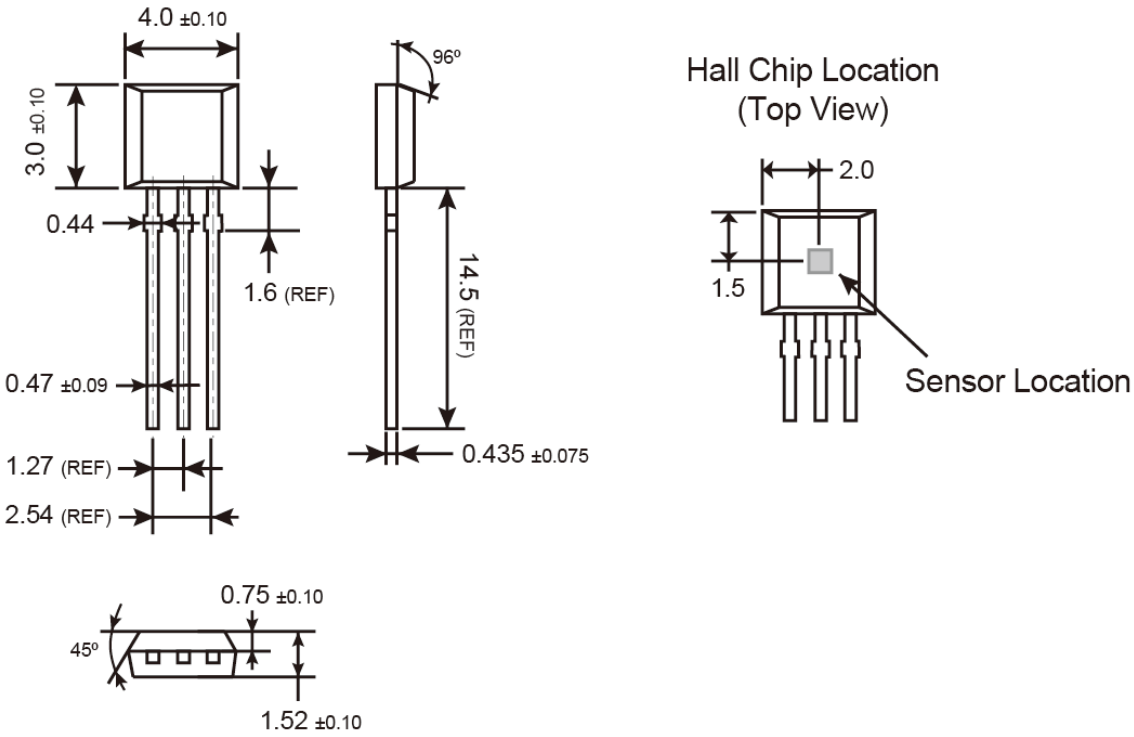


Figure 8. Power Dissipation vs. Temperature

TSH253

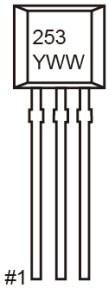
High Sensitivity Omni-Polar Hall Effect Switch

TO-92S Mechanical Drawing



Unit: Millimeters

Marking Diagram

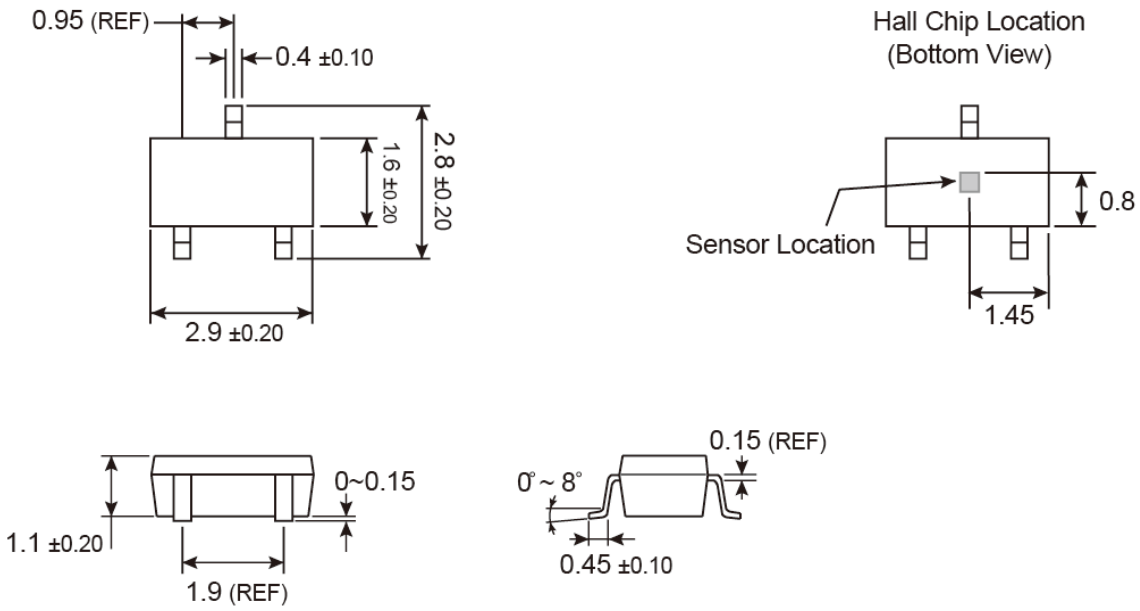


253 = Device Code
Y = Year Code (3=2013, 4=2014….)
WW = Week Code (01~52)

TSH253

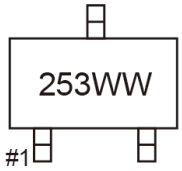
High Sensitivity Omni-Polar Hall Effect Switch

SOT-23 Mechanical Drawing



Unit: Millimeters

Marking Diagram



253 = Device Code

WW = Week Code Table

week	1	2	3	4	5	6	7	8	9	10	11	12	13
code	OA	OB	OC	OD	OE	OF	OG	OH	OI	OJ	OK	OL	OM
week	14	15	16	17	18	19	20	21	22	23	24	25	26
code	ON	OO	OP	OQ	OR	OS	OT	OU	OV	OW	OX	OY	OZ
week	27	28	29	30	31	32	33	34	35	36	37	38	39
code	PA	PB	PC	PD	PE	PF	PG	PH	PI	PJ	PK	PL	PM
week	40	41	42	43	44	45	46	47	48	49	50	51	52
code	PN	PO	PP	PQ	PR	PS	PT	PU	PV	PW	PX	PY	PZ

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